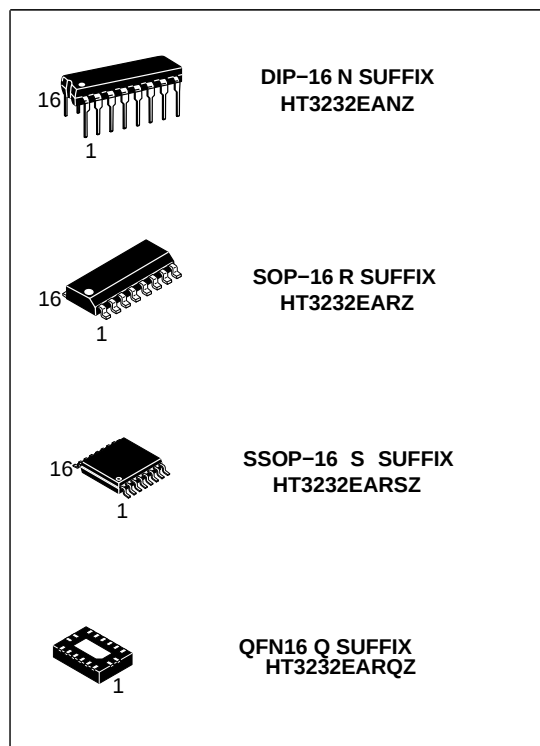


MICROCIRCUIT INTERFACE TRANSCEIVER OF THE SERIAL DATA OF THE STANDARD RS -232

Microcircuits HT3232 is interface transceiver of serial data under RS - 232 standard with single power supply source & bipolar output voltage of transmitter, forming by build-in voltage multiplier on 4 external capacities, 0.1 μ F. HT3232 correspond to EIA/TIA-232E, V.28 standard and is purposed for application in modern high efficient calculating systems with the wide range of supply voltage, fast-operating electronic devices with high level of fidelity of information exchange among distant devices.

Functions and structure:

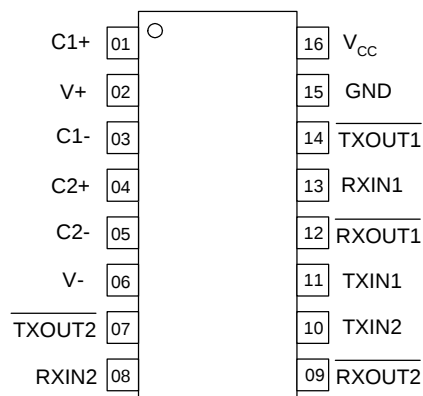
- Microcircuit contains 2 transmitters and 2 receivers of the serial data of the standard RS-232.
- The microcircuit supply voltage range is from 3.0 to 5.5 V.
- Enhanced ESD Specifications:
 - 15kV IEC61000-4-2 Air Discharge
 - 8kV IEC61000-4-2 Contact Discharge

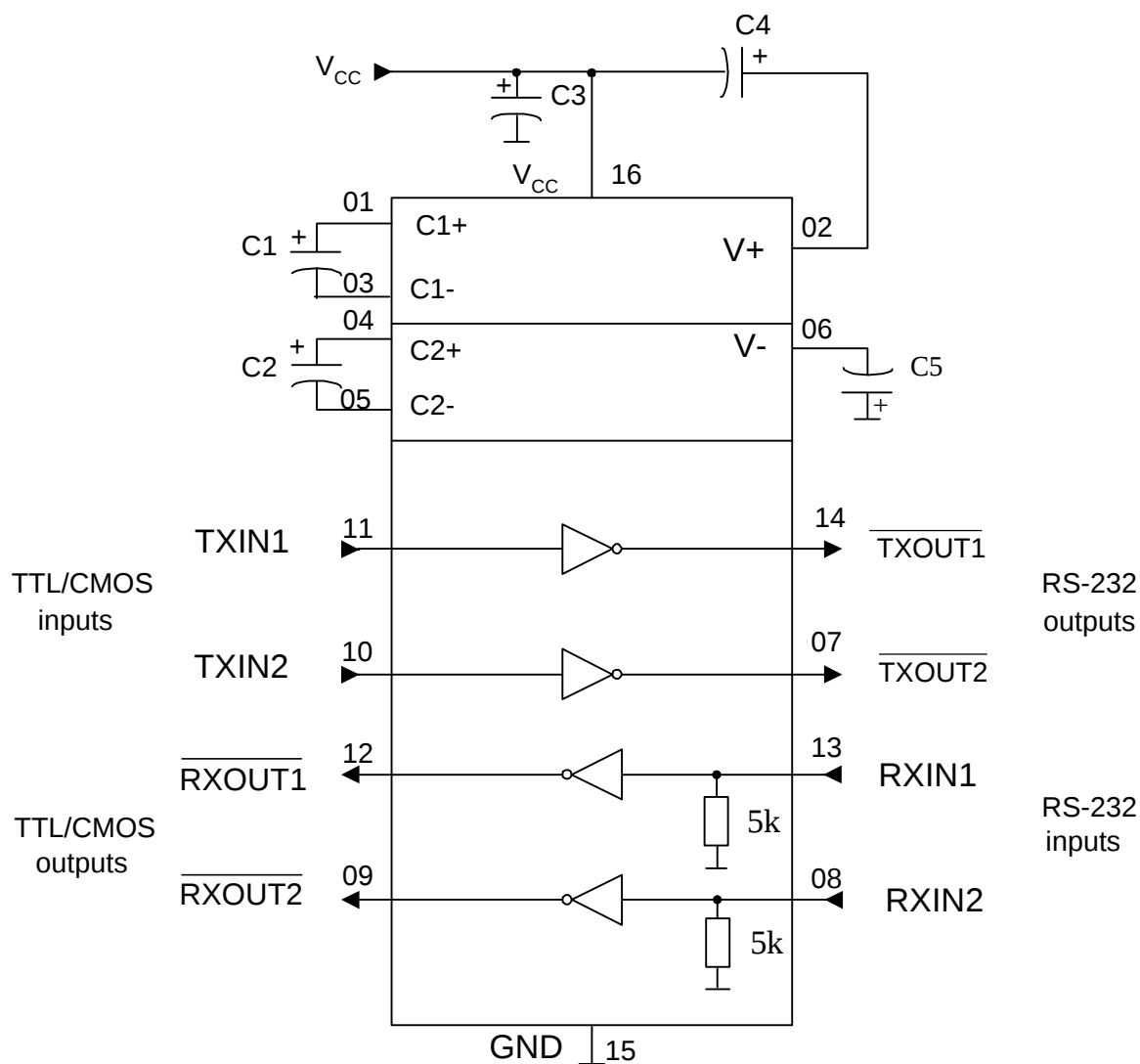


Truth Table

Input	Output
RXIN, TXIN	RXOUT, TXOUT
H	L
L	H
Note – L – low voltage level; H – high voltage level	

Pinning



Functional diagram


C1 – capacitor 0.1 $\mu\text{F} \pm 10\%$ for $U_{CC} = 3.3\text{ V} \pm 10\%$ (0.047 $\mu\text{F} \pm 10\%$ for $U_{CC} = 5.0\text{ V} \pm 10\%$)

C2, C4, C5– capacitors 0.1 $\mu\text{F} \pm 10\%$ for $U_{CC} = 3.3\text{ V} \pm 10\%$ (0.33 $\mu\text{F} \pm 10\%$ for $U_{CC} = 5.0\text{ V} \pm 10\%$)

C3 – capacitor 0.1 $\mu\text{F} \pm 10\%$

Pin description table

Pin number	Pin description	Symbol
01	Positive terminal of the voltage multiplier charge-pump capacitor	C1+
02	Positive voltage multiplier output	V+
03	Negative terminal of the voltage multiplier charge-pump capacitor	C1-
04	Positive terminal of the voltage multiplier charge-pump capacitor	C2+
05	Negative terminal of the voltage multiplier charge-pump capacitor	C2-
06	Negative voltage multiplier output	V-
07	Transmitter output (RS-232 levels)	TXOUT2
08	Receiver input (RS-232 levels)	RXIN2
09	Receiver output (TTL/CMOS levels)	RXOUT2
10	Transmitter input (TTL/CMOS levels)	TXIN2
11	Transmitter input (TTL/CMOS levels)	TXIN1
12	Receiver output (TTL/CMOS levels)	RXOUT1
13	Receiver input (RS-232 levels)	RXIN1
14	Transmitter output (RS-232 levels)	TXOUT1
15	Common pin	GND
16	Supply voltage	V

Maximum Ratings & Recommended Operating Conditions

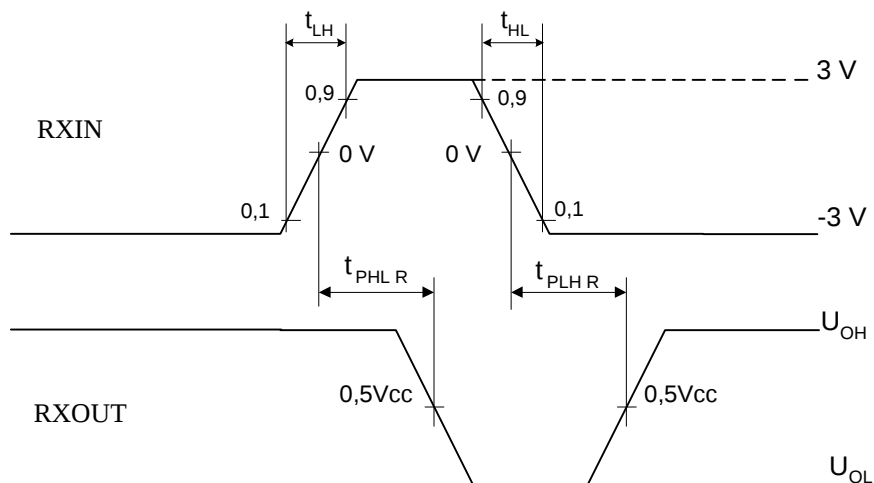
Parameter, unit	Symbol	Recommended operating conditions		Maximum rate	
		min	max	min	max
Supply voltage, V	U_{CC}	3.0	5.5	-0.3	6.0
Voltage applied to transmitter output, V	U	—	—	-13.2	13.2
Multiplier positive output voltage, V	U+	5.0	—	-0.3	7.0
Multiplier negative output voltage, V	U-	-5.0	—	-7.0	0.3
Receiver input voltage, V	U	-25	25	-25	25
Receiver output voltage, V	U	—	—	-0.3	$U_{CC}+0.3$
Transmitter low level input voltage, V	U	0	0.8	-0.3	—
Transmitter high level input voltage, V	U_{IH}	2.0 ($U_{CC}=3.3\text{ V}$)	U_{CC}	—	6
		2.4 ($U_{CC}=5.0\text{ V}$)			
Multiplier outputs voltages difference, V	$U_+ + U_-$	—	—	—	13
Receiver low level threshold input voltage, V	U_{ITL}	0.6 ($U_{CC}=3.3\text{ V}$)	—	—	—
		0.8 ($U_{CC}=5.0\text{ V}$)			
Receiver high level threshold input voltage, V	U_{ITH}	—	2.4	—	—

Electric parameters

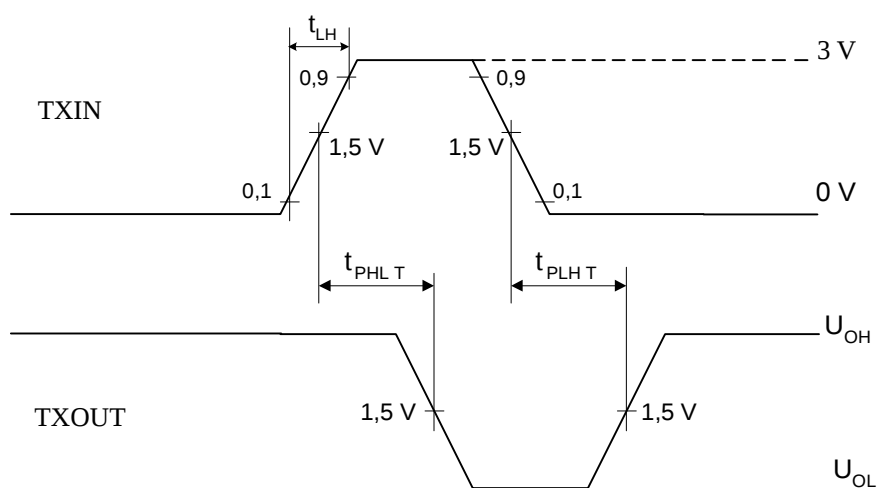
Parameter, unit	Symbol	Norm		Mode	T _A , °C
		Min	Max		
Supply current, μA	I_{CC1}	–	1.0 1.4	$U_{CC} = 3.3\text{ V}; 5.0\text{ V};$ $U_{IL} = 0\text{ V}$	25±10 -40; 85
Receiver					
Low level output voltage, V	U_{OLR}	–	0.3	$U_{CC} = 3.3\text{ V} \pm 10\%; U_{ITH} = 2.4\text{ V};$ $I_L = 1.6\text{ mA}$	25±10
			0.4		-40; 85
			0.3	$U_{CC} = 5.0\text{ V} \pm 10\%; U_{ITH} = 2.4\text{ V};$ $I_L = 1.6\text{ mA}$	25±10
			0.4		-40; 85
High level output voltage, V	U_{OHR1}	2.5	–	$U_{CC} = 3.3\text{ V} \pm 10\%; U_{ITL} = 0.6\text{ V};$ $I_L = -1.0\text{ mA}$	25±10
		2.4			-40; 85
	U_{OHR2}	4.0		$U_{CC} = 5.0\text{ V} \pm 10\%; U_{ITL} = 0.8\text{ V};$ $I_L = -1.0\text{ mA}$	25±10
		3.9			-40; 85
Receiver hysteresis, V	U_h	0.2	1.0	$U_L = 3.3\text{ V} \pm 10\%; 5.0\text{ V} \pm 10\%$	25±10
Input resistance, kOhm	R	3	7	–	25±10
OFF-ON switching propagation delay, ns	t_{PHLR}, t	–	1500	$U_{CC} = 5.0\text{ V} \pm 10\%;$ $C_L = 150\text{ pF};$ $U_{IL} = 0\text{ V};$ $U_{IH} = 3.0\text{ V};$ $t_r = t_f \leq 10\text{ ns}$	
Propagation delays difference, ns	t_{SKD}	–	600		
Transmitter					
Low level output voltage, V	U_{OLT1}	–	-5.07	$U_{CC} = 3.3\text{ V} \pm 10\%; U_{IH} = 2.0\text{ V};$ $R_L = 3\text{ kOhm}$	25±10
			-5.0		-40; 85
	U_{OLT2}	–	-5.07	$U_{CC} = 5.0\text{ V} \pm 10\%; U_{IH} = 2.4\text{ V};$ $R_L = 3\text{ kOhm}$	25±10
			-5.0		-40; 85
High level output voltage, V	U_{OHT}	5.07	–	$U_{CC} = 3.3\text{ V} \pm 10\%; U_{IL} = 0.8\text{ V};$ $R_L = \text{kOhm}$	25±10
		5.0			-40; 85
		5.07	–	$U_{CC} = 5.0\text{ V} \pm 10\%; U_{IL} = 0.8\text{ V};$ $R_L = \text{kOhm}$	25±10
		5.0			-40; 85
Transmitter hysteresis, V	U_h	0.1	1.0	$U_L = 3.3\text{ V} \pm 10\%; 5.0\text{ V} \pm 10\%$	25±10
Low level input leakage current, μA	I_{ILL}	–	-0.5	$U_{CC} = 5.5\text{ V}; U_{IL} = 0\text{ V}$	25±10
			-1.0		-40; 85
High level input leakage current, μA	I_{ILH}	–	0.5	$U_{CC} = 5.5\text{ V}; U_{IH} = 5.5\text{ V}$	25±10
			1.0		-40; 85
Output resistance, Ohm	R_O	350	–	$U_{CC} = U_{V+}^* = U_{V-}^* = 0\text{ V};$ $U_L = \pm 2\text{ V}$	25±10
		300			-40; 85

Electric parameters

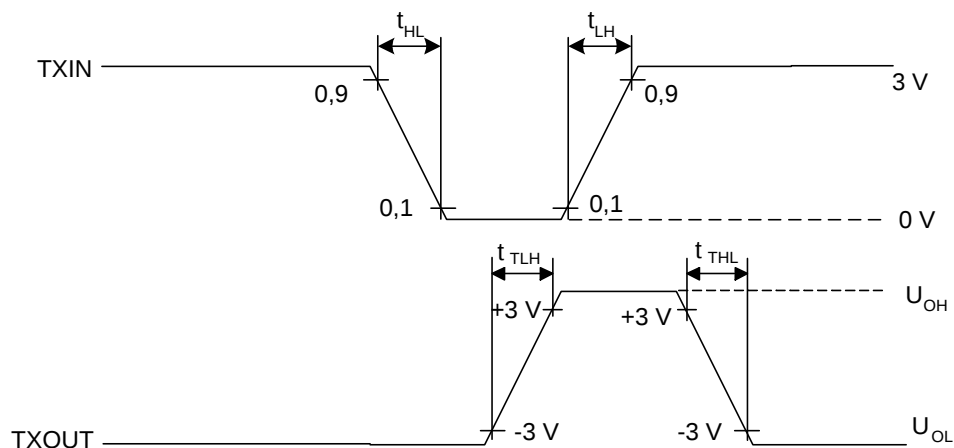
Parameter, unit	Symbol	Norm		Mode	T _A , °C
		Min	Max		
Transmitter					
Short circuit current, mA	I _{OS}	—	53	U _{CC} = 3.6 V	25±10
			60		-40; 85
			-53	U _{CC} = 3.6 V	25±10
			-60		-40; 85
			53	U _{CC} = 5.5 V	25±10
			60		-40; 85
			-53	U _{CC} = 5.5 V	25±10
			-60		-40; 85
Low level output current for OFF-state, µA	I _{OZLT}	—	-10	U _{CC} = 0V; U _O = -12 V; transmitter output is disabled	25±10
			-25		-40; 85
High level output current for OFF-state, µA	I _{OZHT}	—	10	U _{CC} = 0V; U _O = 12 V; transmitter output is disabled	25±10
			25		-40; 85
Maximum Data Rate, Kbit/s	ST	140	—	R _L = 3 kOhm; C _L = 1000 pF	25±10
		120			-40÷85
Transition-Region Slew Rate, V/µs	SR	6	30	U _{CC} = 3.3 V; R _L = (3-7) kOhm; U _{OT} is from +3 to -3 V or from -3 to +3 V; C _L = (150-1000) pF	25±10
		4	30	U _{CC} = 3.3 V; R _L = (3-7) kOhm; U _{OT} is from +3 to -3 V or from -3 to +3 V; C _L = (150-2500) pF	
Propagation delays difference, ns	t _{SKew}	—	600	U _{CC} = 5.0V ±10 %; U _{IL} = 0 V; U _{IH} = 3.0 V; t _{LH} = t _{HL} ≤ 10 ns; R =3 kOhm; C =1000 pF	
* U_{V+}, U_{V-} - voltages applied to pins 02 , 06. Note – Electric parameters is indicated for C1=0.047 µF, C2-C4 = 0.33 µF & U_{CC} = 5.0 V±10 % (or C1-C4 = 0.1 µF & U = 3.3 V±10 %)					



Receiver output & input signals time diagram



Transmitter output & input signals time diagram

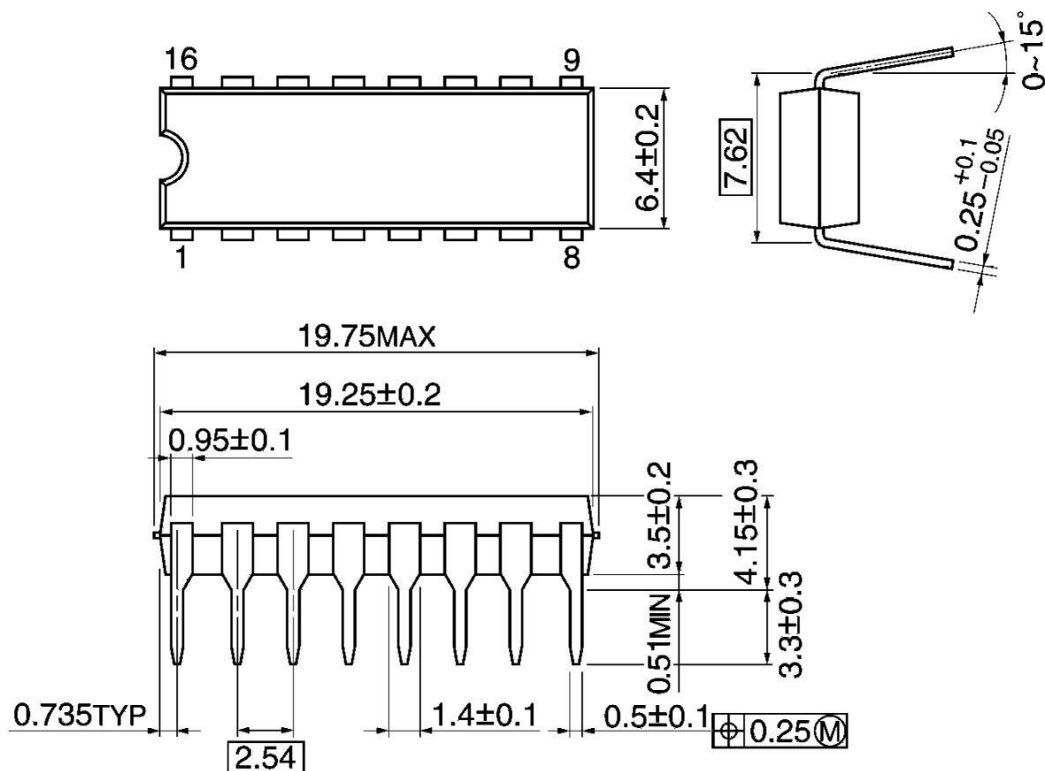


Transmitter output & input signals time diagram

Package Dimensions

DIP16-P-300-2.54A

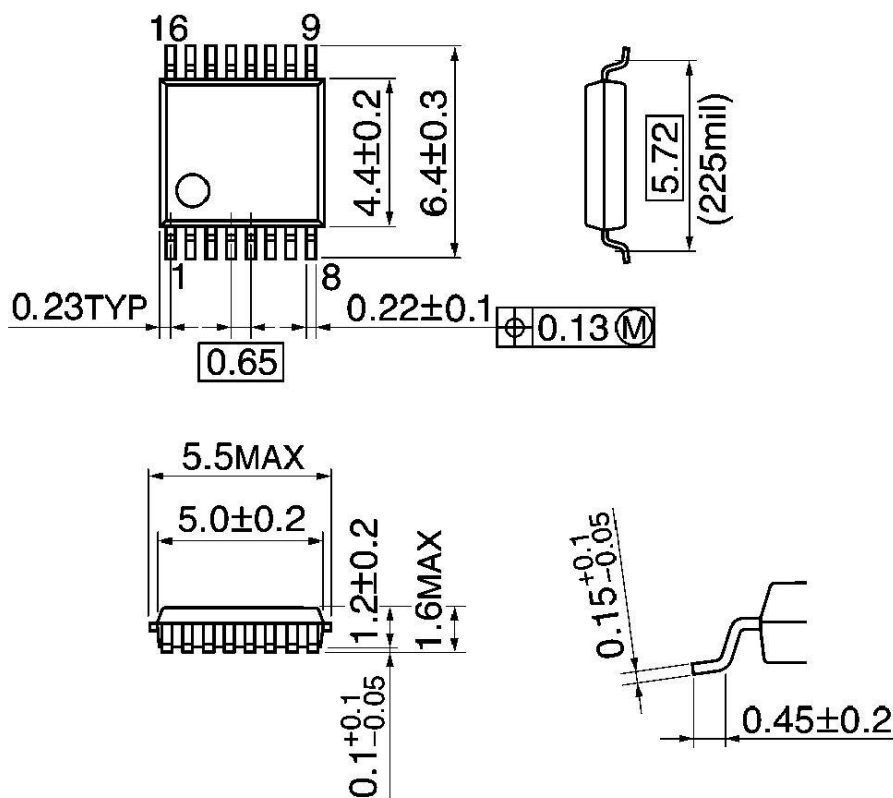
Unit: mm



Weight: 1.11 g (Typ.)

SSOP16-P-225-0.65B

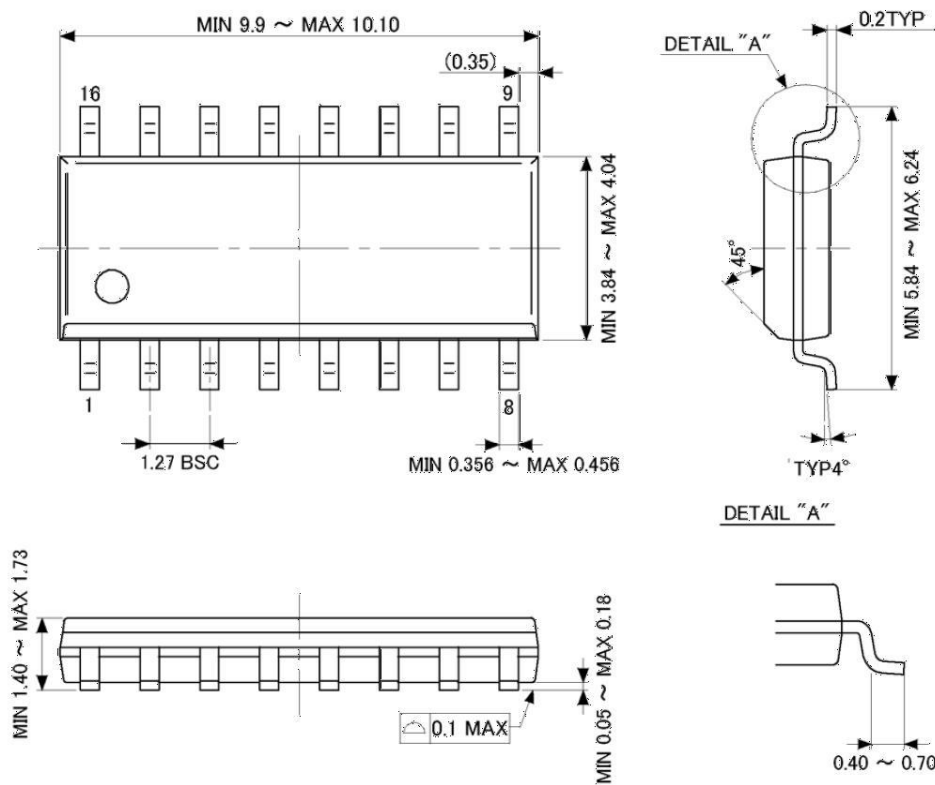
Unit: mm



Weight: 0.07 g (Typ.)

P-SOP16-0410-1.27-002

Unit: mm



Weight: 0.15 g (Typ.)